

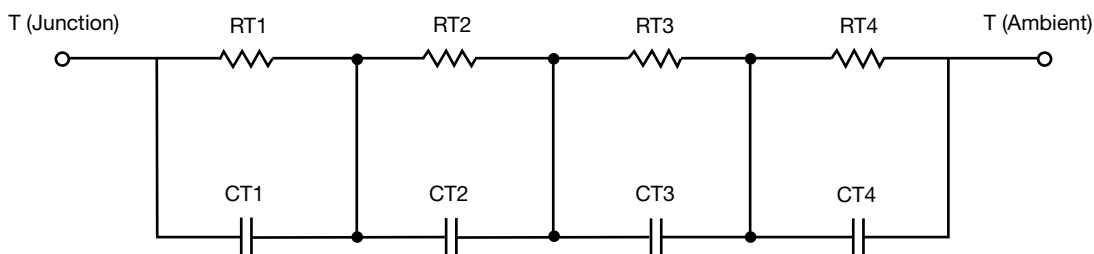
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in PSpice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the PSpice simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the PSpice Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	18.5376	135.3272m	n/a
RT2	16.3651	108.0265m	n/a
RT3	7.0559	75.7268m	n/a
RT4	2.0414	60.9195m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	5.1905	4.7982	n/a
CT2	2.3878	547.7150m	n/a
CT3	199.3868m	1.0087	n/a
CT4	33.5463m	205.0549m	n/a

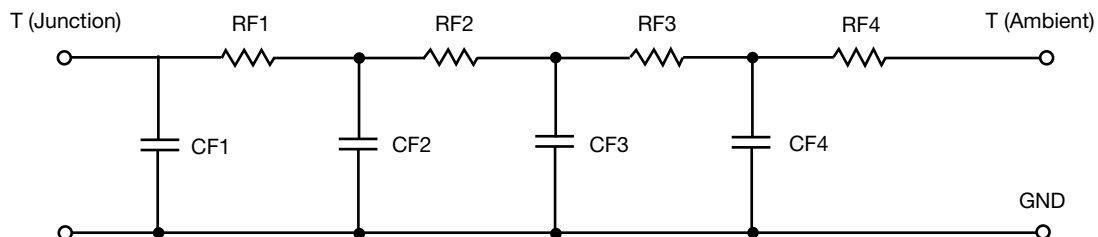
Note

- n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION

THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	2.1358	66.5316m	n/a
RF2	8.0135	100.5608m	n/a
RF3	25.8313	87.9123m	n/a
RF4	8.1609	124.9953m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	24.6130m	103.9792m	n/a
CF2	122.2192m	143.9587m	n/a
CF3	1.4385	4.2599m	n/a
CF4	6.9247	4.3507	n/a

Note

- n/a indicates not applicable

